

Product data sheet

Product profile 1.

1.1 General description

Hyperfast, epitaxial rectifier diode in a SOD113 (2-lead TO-220F) plastic package.

1.2 Features

- Extremely fast switching
- Low reverse recovery current
- Reduces switching loss in associated MOSFET

1.3 Applications

- Half-bridge or full-bridge switched-mode Continuous Current Mode (CCM) Power power supplies Factor Correction (PFC)
- Half-bridge lighting ballasts

1.4 Quick reference data



t_{rr} = 19 ns (typ)

Low thermal resistance

Isolated package

Pinning information 2.

| Table 1. | Pinning | | |
|----------|-------------------------|--------------------|--------------------------------------|
| Pin | Description | Simplified outline | Symbol |
| 1 | cathode (k) | | . 14 |
| 2 | anode (a) | mb | k ─── ─ a <i>001aaa020</i> |
| mb | mounting base; isolated | | |

SOD113 (2-lead TO-220F)



3. Ordering information

| Table 2. Ordering information | | | | | | |
|-------------------------------------|---------|---|---------|--|--|--|
| Type number | Package | | | | | |
| | Name | Description | Version | | | |
| BYC20X-600 | TO-220F | plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 'full pack' | SOD113 | | | |

4. Limiting values

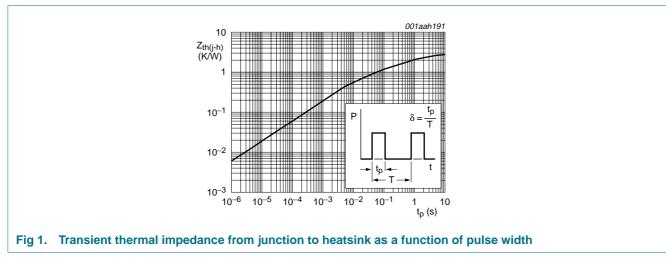
Table 3.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|--------------------|---------------------------------|---|-----|------|------|
| V _{RRM} | repetitive peak reverse voltage | | - | 600 | V |
| V _{RWM} | crest working reverse voltage | | - | 600 | V |
| V _R | reverse voltage | square waveform; δ = 1.0; $T_h \leq$ 100 $^\circ C$ | - | 500 | V |
| I _{F(AV)} | average forward current | square waveform; δ = 0.5; T_h \leq 25 $^\circ C$ | - | 20 | А |
| I _{FRM} | repetitive peak forward current | square waveform; δ = 0.5; $T_h \leq$ 25 °C; t_p = 25 μs | - | 40 | А |
| I _{FSM} | non-repetitive peak forward | t = 10 ms; sinusoidal waveform | - | 250 | А |
| | current | t = 8.3 ms; sinusoidal waveform | - | 274 | А |
| T _{stg} | storage temperature | | -40 | +150 | °C |
| Tj | junction temperature | | - | 150 | °C |
| | | | | | |

Thermal characteristics 5.

| Table 4. | Thermal characteristics | | | | | |
|----------------------|--|--|-----|-----|-----|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| R _{th(j-h)} | thermal resistance from junction to heatsink | with heatsink compound; see <u>Figure 1</u> | - | - | 2.6 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 55 | - | K/W |



Isolation characteristics 6.

Isolation limiting values and characteristics Table 5. $T_{h} = 25 \circ C$ unless otherwise specified

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------------|-----------------------|--|-----|-----|------|------|
| V _{isol(RMS)} | RMS isolation voltage | from all terminals to external heatsink; f = 50 Hz to 60 Hz; sinusoidal waveform; relative humidity \leq 65 %; clean and dust free | - | - | 2500 | V |
| C _{isol} | isolation capacitance | from pin 1 (cathode) to external heatsink; f = 1 MHz | - | 10 | - | pF |

Characteristics 7.

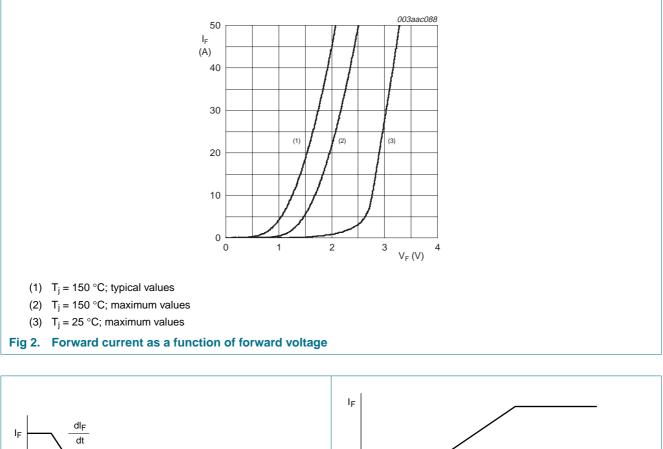
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------|----------------------------------|--|-----|------|------|------|
| Static cha | racteristics | | | | | |
| V _F | forward voltage | I _F = 20 A; T _j = 150 °C; see <u>Figure 2</u> | - | 1.54 | 1.97 | V |
| | | $I_F = 40 \text{ A}; T_j = 150 \text{ °C}; \text{ see } \frac{\text{Figure 2}}{\text{Figure 2}}$ | - | 1.95 | 2.34 | V |
| | | I _F = 20 A; see <u>Figure 2</u> | - | 1.89 | 2.9 | V |
| I _R | reverse current | V _R = 600 V | - | 16 | 200 | μA |
| | | V_R = 500 V; T _j = 100 °C | - | 1.6 | 3.0 | mA |
| Dynamic o | haracteristics | | | | | |
| t _{rr} | reverse recovery time | $I_F = 1 \text{ A to } V_R = 30 \text{ V}; \text{ d}_F/\text{d}t = 50 \text{ A}/\mu\text{s};$ see Figure 3 | - | 35 | 55 | ns |
| | | $I_F = 20 \text{ A to } V_R = 400 \text{ V}; \text{ d}I_F/\text{d}t = 500 \text{ A}/\mu\text{s};$ see Figure 3 | | | | |
| | | T _j = 25 °C | - | 19 | - | ns |
| | | T _j = 100 °C | - | 32 | 40 | ns |
| I _{RM} | peak reverse recovery current | I_F = 20 A to V_R = 400 V; T_j = 125 °C; see <u>Figure 3</u> | | | | |
| | | $dI_F/dt = 50 A/\mu s$ | - | 3.0 | 7.5 | А |
| | | $dI_F/dt = 500 \text{ A}/\mu\text{s}$ | - | 9.5 | 12 | А |
| V_{FR} | forward recovery voltage | $I_F = 20 \text{ A}; \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}; \text{ see } \frac{\text{Figure 4}}{100 \text{ A}}$ | - | 8 | 11 | V |

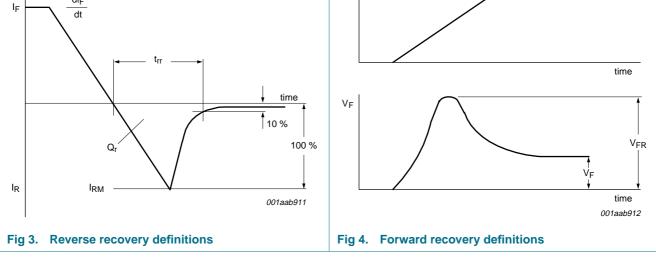
Table 6 Characteristics

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Rectifier diode, hyperfast

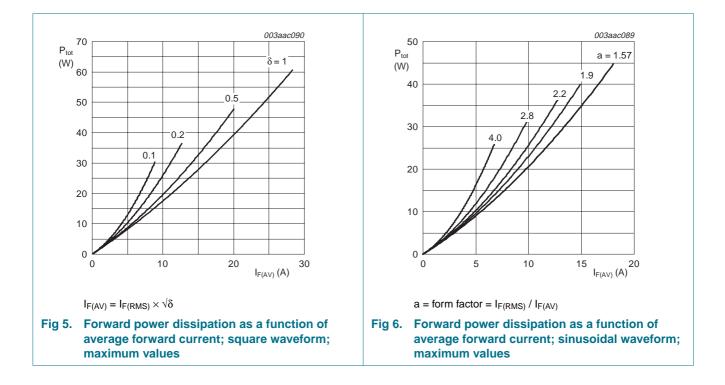




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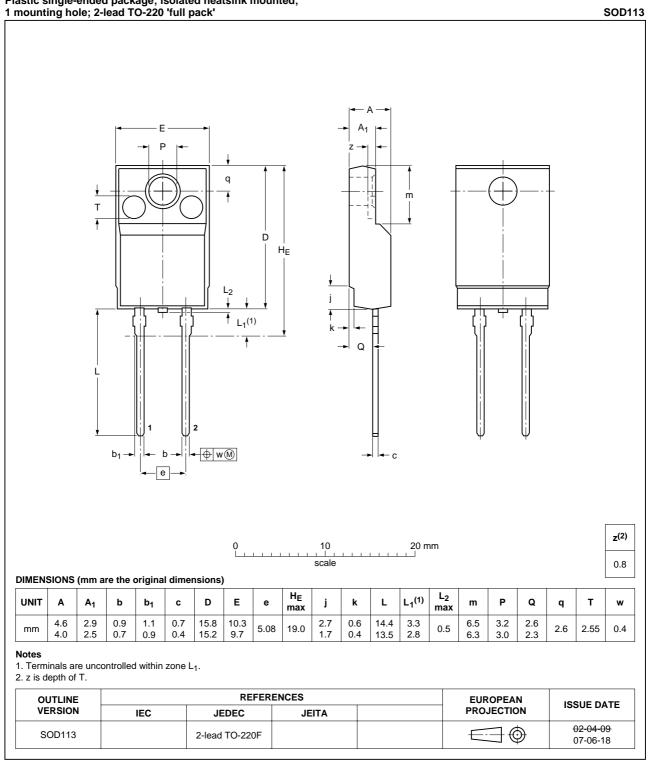
BYC20X-600

Rectifier diode, hyperfast





Package outline 8.



Plastic single-ended package; isolated heatsink mounted; 1 mounting hole; 2-lead TO-220 'full pack'

Fig 7. Package outline SOD113 (2-lead TO-220F)



9. Revision history

| Table 7. Revision history | | | | |
|---------------------------|--------------|--------------------|---------------|------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| BYC20X-600_1 | 20071129 | Product data sheet | - | - |

10. Legal information

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| Document status[1][2] | Product status ^[3] | Definition |
|--------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
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| Product [short] data sheet | Production | This document contains the product specification. |

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